

# Silicon Carbide Schottky Diode

# 650 V, 10 A

## FFSB1065A

#### **Description**

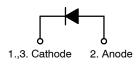
Silicon Carbide (SiC) Schottky Diodes use a completely new technology that provides superior switching performance and higher reliability compared to Silicon. No reverse recovery current, temperature independent switching characteristics, and excellent thermal performance sets Silicon Carbide as the next generation of power semiconductor. System benefits include highest efficiency, faster operating frequency, increased power density, reduced EMI, and reduced system size and cost.

#### **Features**

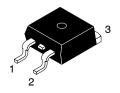
- Max Junction Temperature 175°C
- Avalanche Rated 64 mJ
- High Surge Current Capacity
- Positive Temperature Coefficient
- Ease of Paralleling
- No Reverse Recovery/No Forward Recovery
- This Device is Pb–Free, Halogen Free/BFR Free and RoHS Compliant

#### **Applications**

- General Purpose
- SMPS, Solar Inverter, UPS
- Power Switching Circuits

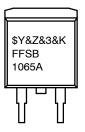


**Schottky Diode** 



TO-263, 3-LEAD CASE 418BK

#### **MARKING DIAGRAM**



\$Y = ON Semiconductor Logo &Z = Assembly Plant Code &3 = Numeric Date Code &K = Lot Code

FFSB1065A = Specific Device Code

#### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 2 of this data sheet.

#### FFSB1065A

#### ABSOLUTE MAXIMUM RATINGS ( $T_C = 25$ °C unless otherwise noted)

Symbol	Parameter	Value	Unit	
$V_{RRM}$	Peak Repetitive Reverse Voltage		650	V
E <sub>AS</sub>	Single Pulse Avalanche Energy (Note 1)	Single Pulse Avalanche Energy (Note 1)		mJ
lF	Continuous Rectified Forward Current @ T <sub>C</sub> < 152°C		10	А
	Continuous Rectified Forward Current @ T <sub>C</sub> < 135°C		14	
I <sub>F, Max</sub>	Non-Repetitive Peak Forward Surge Current	T <sub>C</sub> = 25°C, 10 μs	760	Α
		T <sub>C</sub> = 150°C, 10 μs	740	Α
I <sub>F,SM</sub>	Non-Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	56	Α
I <sub>F,RM</sub>	Repetitive Forward Surge Current	Half-Sine Pulse, t <sub>p</sub> = 8.3 ms	38	Α
Ptot	Power Dissipation	T <sub>C</sub> = 25°C	106	W
		T <sub>C</sub> = 150°C	18	W
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	•	-55 to +175	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
$R_{ heta JC}$	Thermal Resistance, Junction to Case, Max	1.4	°C/W

#### **ELECTRICAL CHARACTERISTICS** (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Test Condition	Min	Тур	Max	Unit
V <sub>F</sub>	Forward Voltage	I <sub>F</sub> = 10 A, T <sub>C</sub> = 25°C	-	1.5	1.75	V
		I <sub>F</sub> = 10 A, T <sub>C</sub> = 125°C	_	1.6	2.0	
		I <sub>F</sub> = 10 A, T <sub>C</sub> = 175°C	_	1.72	2.4	
I <sub>R</sub>	Reverse Current	V <sub>R</sub> = 650 V, T <sub>C</sub> = 25°C	-	-	200	μΑ
		V <sub>R</sub> = 650 V, T <sub>C</sub> = 125°C	-	-	400	
		V <sub>R</sub> = 650 V, T <sub>C</sub> = 175°C	-	-	600	
$Q_{C}$	Total Capacitive Charge	V = 400 V	-	34	-	nC
С	Total Capacitance	V <sub>R</sub> = 1 V, f = 100 kHz	-	575	-	pF
		V <sub>R</sub> = 200 V, f = 100 kHz	-	62	-	
		V <sub>R</sub> = 400 V, f = 100 kHz	_	47	_	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

#### PACKAGE MARKING AND ORDERING INFORMATION

Part Number	Top Marking	Package	Reel Size	Tape Width	Shipping <sup>†</sup>
FFSB1065A	FFSB1065A	D <sup>2</sup> PAK-3 (TO-263, 3-LEAD) Pb-Free/Halogen Free	330 mm	24 mm	800 Units / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>1.</sup>  $E_{AS}$  of 64 mJ is based on starting  $T_J = 25^{\circ}C$ , L = 0.5 mH,  $I_{AS} = 16$  A, V = 50 V.

#### FFSB1065A

### **TYPICAL CHARACTERISTICS**

 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$ 

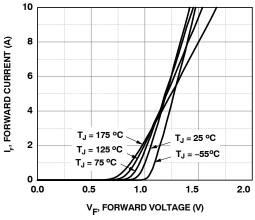


Figure 1. Forward Characteristics

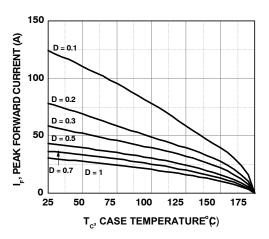


Figure 3. Current Derating

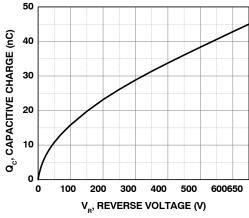


Figure 5. Capacitive Charge vs. Reverse Voltage

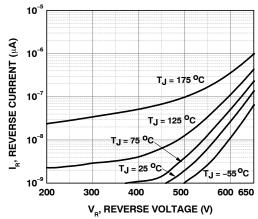


Figure 2. Reverse Characteristics

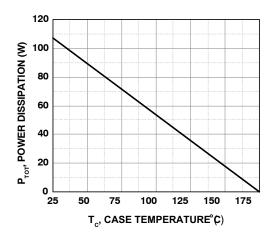


Figure 4. Power Derating

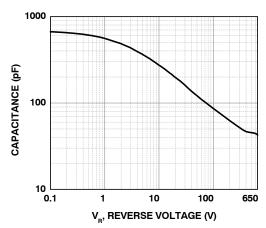


Figure 6. Capacitance vs. Reverse Voltage

#### FFSB1065A

#### **TYPICAL CHARACTERISTICS**

 $(T_J = 25^{\circ}C \text{ unless otherwise noted})$ 

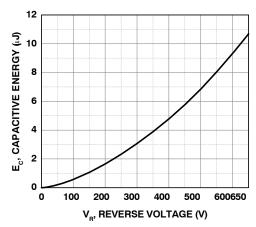


Figure 7. Capacitance Stored Energy

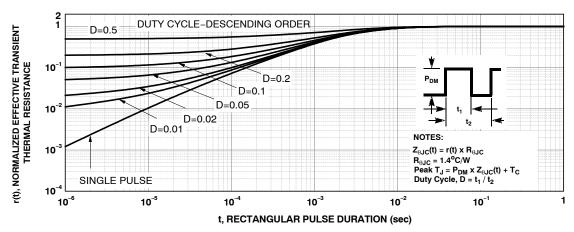


Figure 8. Junction-to-Case Transient Thermal Response Curve

#### **TEST CIRCUIT AND WAVEFORMS**

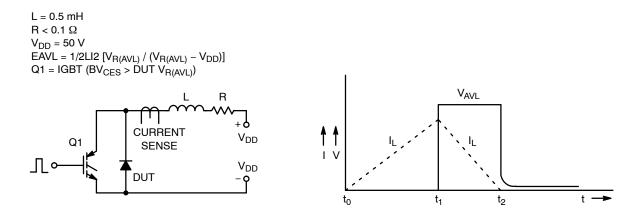
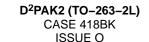
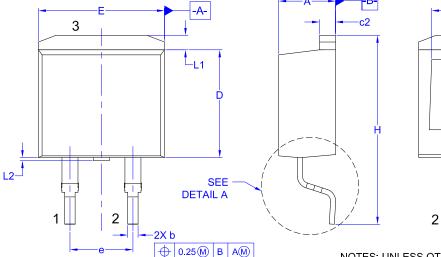
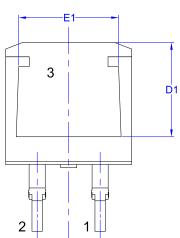


Figure 9. Unclamped Inductive Switching Test Circuit & Waveform



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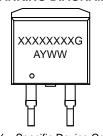


NOTES: UNLESS OTHERWISE SPECIFIED

- A) ALL DIMENSIONS ARE IN MILLIMETERS.
  B) REFERENCE JEDEC, TO-263, VARIATION AB.
- C) DIMENSIONING AND TOLERANCING PER
  DIMENSIONING AND TOLERANCING PER
- ASME Y14.5 2009.
  D) LANDPATTERN RECOMMENDATION PER IPC
- D) LANDPATTERN RECOMMENDATION PER IPO TO254P1524X482-3N

DETAIL A, ROTATED 90°	B)
SCALE: 2X	'(
GAUGE PLANE	D)
M	L3
B 0.10 SEATING —	-A1
GENERIC PLANE	—10.67—— <del>-</del>

GENERIC
MARKING DIAGRAM*



XXX = Specific Device Code

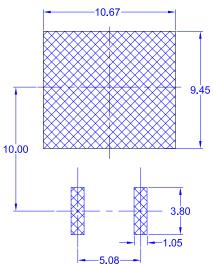
A = Assembly Location

Y = Year

WW = Work Week

G = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot " ■", may or may not be present. Some products may not follow the Generic Marking.



LAND PATTERN RECOMMENDATION
UNLESS NOTED. ALL DIMS TYPICAL

MIN	NOM	MAX
4.06	4.57	4.83
0.00	0.10	0.25
0.51	0.81	0.99
0.30	0.407	0.74
1.14	1.30	1.65
8.38	8.69	9.65
7.30	7.80	8.30
9.65	10.16	10.67
8.00	8.62	9.00
5.08 BSC		
14.60	15.35	15.88
1.78	2.54	2.79
0.90	1.29	1.68
0.00	0.15	0.25
0.25 BSC		
0° 4°		8°
	4.06 0.00 0.51 0.30 1.14 8.38 7.30 9.65 8.00 14.60 1.78 0.90 0.00	4.06     4.57       0.00     0.10       0.51     0.81       0.30     0.407       1.14     1.30       8.38     8.69       7.30     7.80       9.65     10.16       8.00     8.62       5.08 BS       14.60     15.35       1.78     2.54       0.90     1.29       0.00     0.15       0.25 BS

**MILLIMETERS** 

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